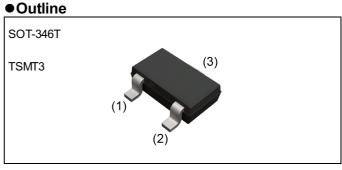
Nch 30V 2.5A Small Signal MOSFET

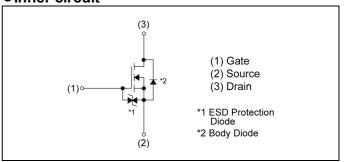
V <sub>DSS</sub>	30V
R <sub>DS(on)</sub> (Max.)	70mΩ
I <sub>D</sub>	±2.5A
P <sub>D</sub>	1.0W



### Features

- 1) Low on resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (TSMT3).

## •Inner circuit



Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	180
Туре	Tape width (mm)	8
	Basic ordering unit (pcs)	3000
	Taping code	TL
	Marking	QY

# Application

Switching

## ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V <sub>DSS</sub>	30	V
Continuous drain current	I <sub>D</sub>	±2.5	Α
Pulsed drain current	I <sub>DP</sub> *1	±10	Α
Gate - Source voltage	V <sub>GSS</sub>	20	V
Douge discipation	P <sub>D</sub> *2	1.0	W
Power dissipation	P <sub>D</sub> *3	0.76	W
Junction temperature	T <sub>j</sub>	150	°C
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	°C

## ●Thermal resistance

Deremeter	Cumb of	Values			Linit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal registance innetion, ambient	R <sub>thJA</sub> *2	1	1	125	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub> *3	ı	1	165	°C/W

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Darameter	Symbol	Conditions	Values			Unit	
Parameter	Parameter Symbol		Min.	Тур.	Max.	Offit	
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	30	-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	I <sub>D</sub> = 1mA referenced to 25°C	-	29.0	-	mV/°C	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	1	-	1	μA	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = 20V, V_{DS} = 0V$	1	-	10	μA	
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = 10V, I_{D} = 1mA$	1.0	-	2.5	V	
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	-1.6	-	mV/°C	
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 2.5A	-	50	70		
Static drain - source on - state resistance	R <sub>DS(on)</sub> *4	$V_{GS} = 4.5V, I_D = 2.5A$	1	74	105	mΩ	
		$V_{GS} = 4.0V, I_D = 2.5A$	1	83	118		
Gate resistance	$R_G$	f = 1MHz, open drain	1	16.7	1	Ω	
Forward Transfer Admittance	Y <sub>fs</sub>  *4	$V_{DS} = 10V, I_D = 2.5A$	1.5	-	-	S	

<sup>\*1</sup> Pw ≤ 10µs, Duty cycle ≤ 2%

<sup>\*2</sup> Mounted on a ceramic board (30×30×0.8mm)

<sup>\*3</sup> Mounted on a FR4 (25×25×0.8mm,Cu pad:625mm<sup>2</sup>)

<sup>\*4</sup> Pulsed

# ●Electrical characteristics (T<sub>a</sub> = 25°C)

Davamatav	Cumbal	Conditions	Values			l leit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	165	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 10V	-	55	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	35	-	
Turn - on delay time	t <sub>d(on)</sub> *4	V <sub>DD</sub> ≈ 15V,V <sub>GS</sub> = 10V	-	6	-	
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 1.25A	-	10	-	no
Turn - off delay time	t <sub>d(off)</sub> *4	$R_L \simeq 12.0\Omega$	-	20	-	ns
Fall time	t <sub>f</sub> *4	$R_G = 10\Omega$	-	5	-	

# • Gate charge characteristics $(T_a = 25^{\circ}C)$

	\ a	,					
Parameter	Symbol	Conditions	Values			l leit	
raiametei	Symbol	Conditions	Min.	Тур.	Max.	- Unit	
Total gate charge	Qg*4	V <sub>DD</sub> ≃ 15V.	-	2.9	4.1		
Gate - Source charge	Q <sub>gs</sub> *4	V <sub>DD</sub> ≃ 15V, I <sub>D</sub> = 2.5A,	-	0.8	-	nC	
Gate - Drain charge	Q <sub>gd</sub> *4	$V_{GS} = 5V$	-	0.9	-		

# ●Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Darameter	Symbol	Conditions	Values			Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	- Unit
Continuous forward current	I <sub>S</sub>	T - 25°C	-	-	0.8	Α
Pulse forward current	I <sub>SP</sub> *1	T <sub>a</sub> = 25°C	-	-	3.2	Α
Forward voltage	V <sub>SD</sub> *4	V <sub>GS</sub> = 0V, I <sub>S</sub> = 3.2A	-	-	1.2	V

#### • Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

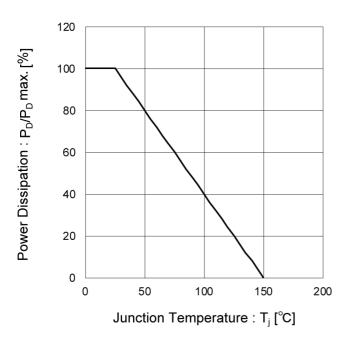
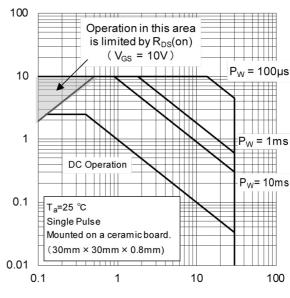


Fig.2 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Drain - Source Voltage: V<sub>DS</sub> [V]

Fig.3 Normalized Transient Thermal
Resistance vs. Pulse Width

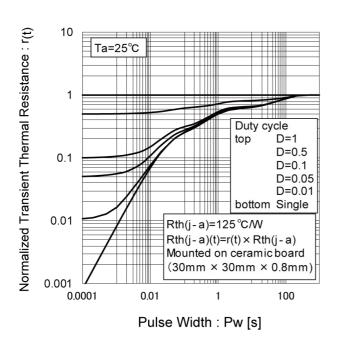
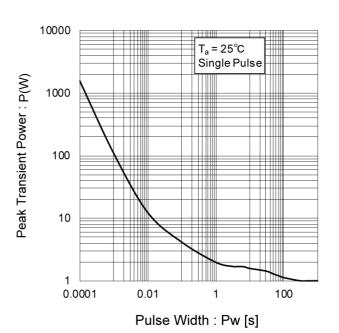


Fig.4 Single Pulse Maximum Power dissipation



### • Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

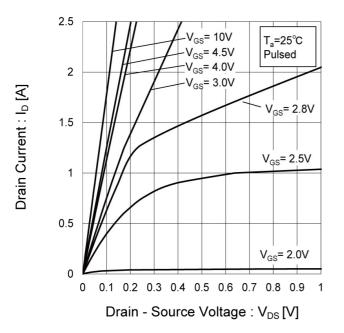
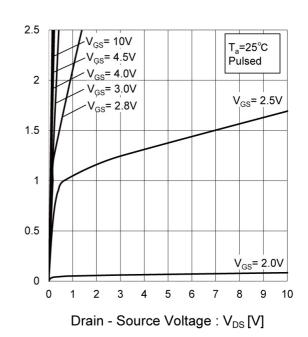


Fig.6 Typical Output Characteristics(II)



Drain Current : I<sub>D</sub> [A]

Fig.7 Breakdown Voltage vs. Junction Temperature

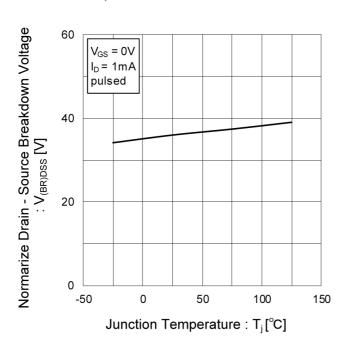
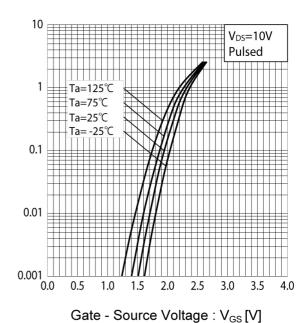


Fig.8 Typical Transfer Characteristics

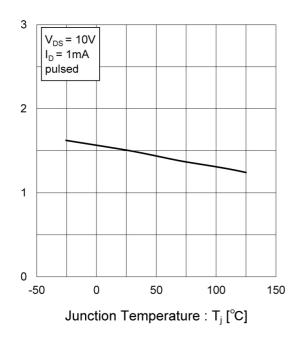


Drain Current : I<sub>D</sub> [A]

Gate Threshold Voltage: V<sub>GS(th)</sub> [V]

### • Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs. Junction Temperature



Forward Transfer Admittance : |Y<sub>fs</sub>| [S]

Fig.10 Forward Transfer Admittance vs. Drain Current

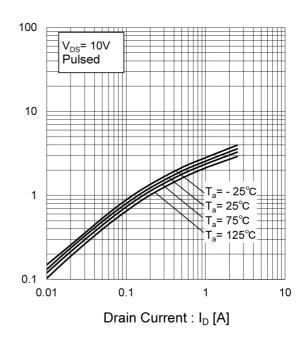


Fig.11 Drain Current Derating Curve

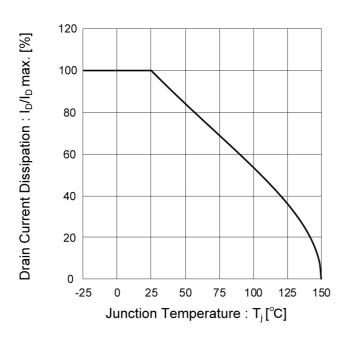
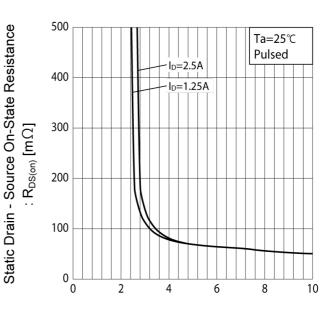


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Gate - Source Voltage : V<sub>GS</sub> [V]

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### • Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

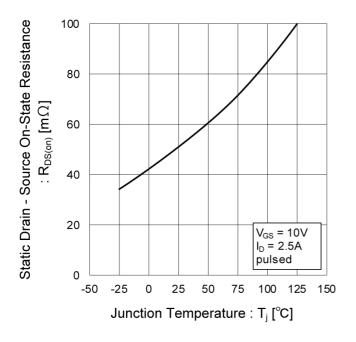
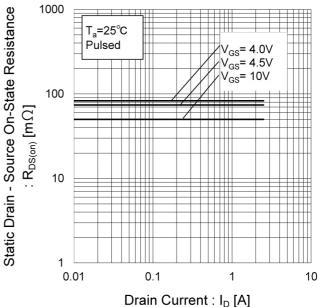


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(I)



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RSR025N03FRATL Datasheet

Static Drain - Source On-State Resistance

### • Electrical characteristic curves

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

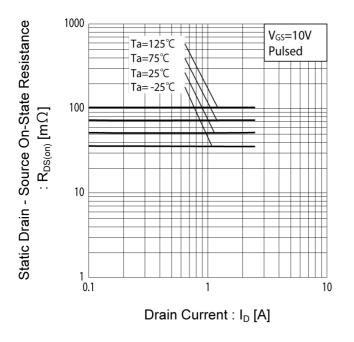


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)

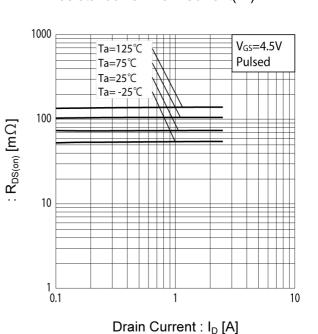
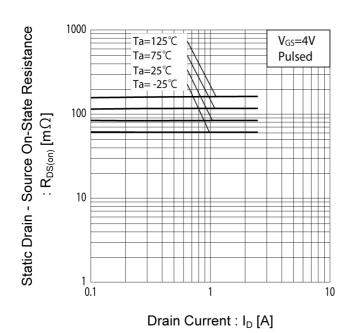


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV)



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### • Electrical characteristic curves

Fig.18 Typical Capacitance vs. Drain - Source Voltage

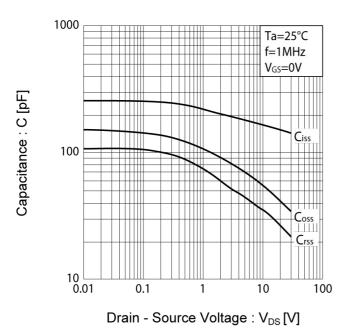
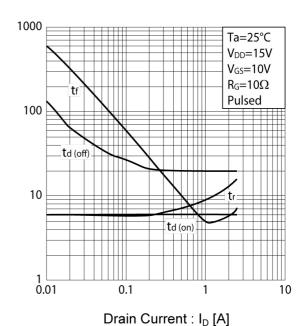


Fig.19 Switching Characteristics



Switching Time : t [ns]

Fig.20 Dynamic Input Characteristics

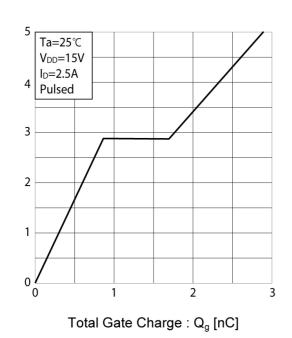
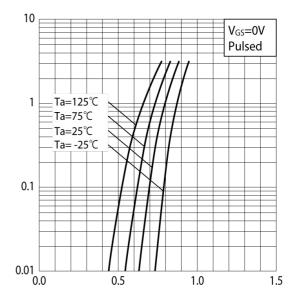


Fig.21 Source Current vs. Source Drain Voltage



Source - Drain Voltage : V<sub>SD</sub> [V]

Gate - Source Voltage :  $V_{GS}$  [V]

Source Current : Is [A]

### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

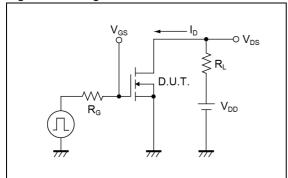


Fig.2-1 Gate Charge Measurement Circuit

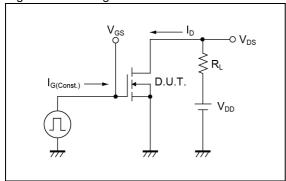


Fig.1-2 Switching Waveforms

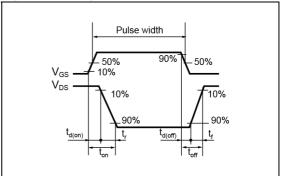
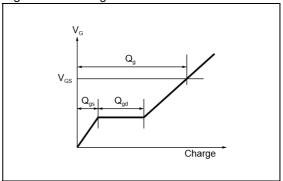


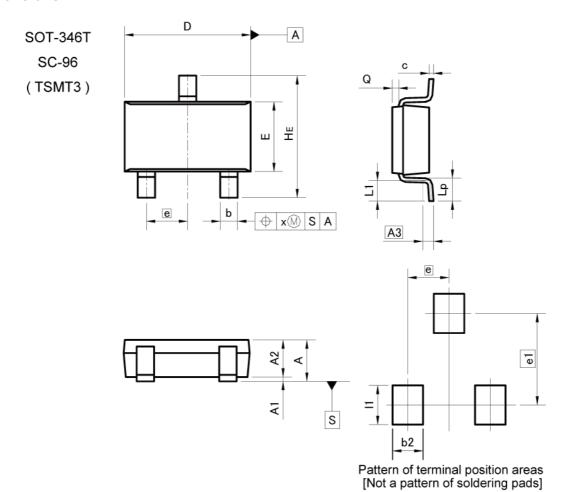
Fig.2-2 Gate Charge Waveform



### Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

### Dimensions



DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	-	1.00	-	0.039
A1	0.00	0.10	0.000	0.004
A2	0.75	0.95	0.030	0.037
A3	0.:	25	0.0	10
b	0.35	0.50	0.014	0.020
С	0.10	0.26	0.004	0.010
D	2.80	3.00	0.110	0.118
Е	1.50	1.80	0.059	0.071
е	0.9	95	0.0	37
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.05	0.25	0.002	0.010
×		0.20	===	0.008

DIM	MILIMETERS		MILIMETERS INCH	
DIM	MIN	MAX	MIN	MAX
b2		0.70	-	0.028
e1	2.10		0.0	83
I1	<del>-</del> -2	0.90	<del></del>	0.035

Dimension in mm/inches



# **Notice**

#### **Precaution on using ROHM Products**

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

Ť	JÁPAN	USA	EU	CHINA
	CLASSⅢ	CLASSIII	CLASS II b	СГУССШ
	CLASSIV	CLASSIII	CLASSIII	CLASSII

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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#### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

#### **Precaution for Disposition**

When disposing Products please dispose them properly using an authorized industry waste company.

#### **Precaution for Foreign Exchange and Foreign Trade act**

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# RSR025N03FRA - Web Page

**Distribution Inventory** 

Part Number	RSR025N03FRA
Package	TSMT3
Unit Quantity	3000
Minimum Package Quantity	3000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

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BD9009HFP-EVK-001 BD9285F-GE2 KTR10EZPF2203 SML-810TBT86 RB168L-60TE25 MCR100JZHF1301 MCR100JZHJ4R3

MCR100JZHJ513 MCR100JZHJ683 MCR10EZHFSR062 BD9B300MUV-EVK-001 MNR12ERAPJ100 RF1501TF3S MNR34J5ABJ221

BD9060HFP-EVK-001 BD9611MUV-EVK-001 BD9778HFP-TR BD9C601EFJ-EVK-001 BD9D321EFJ-EVK-101 BA7603F-E2

BD95820N-LB BD9A100MUV-EVK-001 BD9C401EFJ-EVK-001 BD9C501EFJ-EVK-001 BU90005GWZ-E2-EVK-101 846-1001-KIT

LA-401XD SLA560WBD2PT2 BH1790GLC-EVK-001 BD9B301MUV-EVK-101 BA7071F-E2 SK-AD01-D62Q1367TB BM2P129TF-EVK-001